## NSN 5962-01-030-2105

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-030-2105 **Body Length:** 0.830 inches **Body Width:** Between 0.260 inches and 0.293 inches **Body Height:** 0.180 inches **Storage Tempurature Range:** -65.0/+150.0 degrees celsius **End Application:** Data displal group type an/uya- (v) **Features Provided:** Hermetically sealed and monolithic and expandable and positive outputs and programmable and w/buffered output and w/enable and programmed **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** -1.5 volts power source and 7.0 volts power source **Time Rating Per Chacteristic:** 35.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Rom **Test Data Document:** 05869-717382-16 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a **Unit Of Measure:** 

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**Demilitarization:** Yes - demil/mli